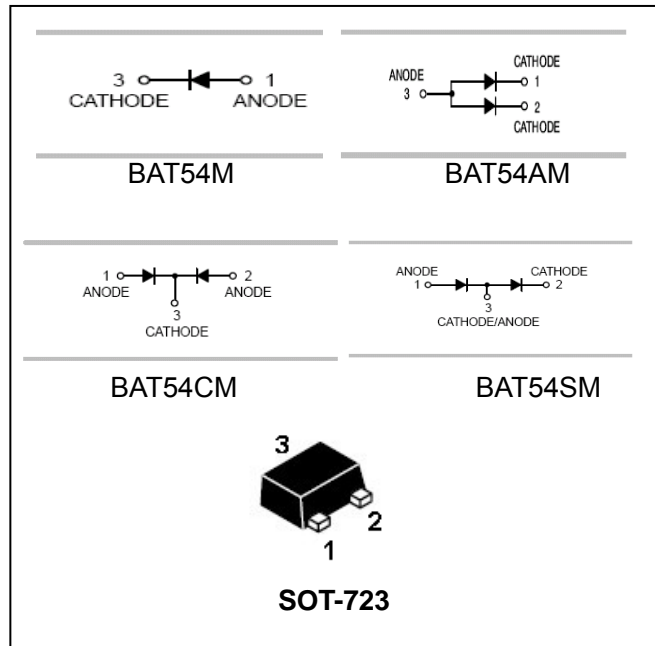


Surface Mount Schottky Barrier diode

**BAT54M/AM/CM/SM**

**FEATURES**

- Fast switching .
- Low Turn-on voltage.
- PN Junction Guard Ring for Transient and ESD Protection.
- Available in Lead Free Version.



**ORDERING INFORMATION**

Type No.	Marking	Package Code
BAT54M	KL1	SOT-723
BAT54AM	KL2	SOT-723
BAT54CM	KL3	SOT-723
BAT54SM	KL4	SOT-723

**MAXIMUM RATING @ Ta=25°C unless otherwise specified**

Parameter	Symbol	Limits	Unit
Peak Repetitive Peak reverse voltage	$V_{RRM}$	30	V
Working Peak Reverse Voltage	$V_{RWM}$		
DC Reverse Voltage	$V_R$		
Forward Continuous Current	$I_F$	200	mA
Repetitive Peak Forward Current	$I_{FRM}$	300	mA
Forward surge current	@t<1.0s $I_{FSM}$	600	mA
Power Dissipation	$P_d$	150	mW
Thermal resistance, junction to ambient air	$R_{\theta JA}$	500	°C/W
Operating and Storage temperature	$T_J, T_{STG}$	-65 to +125	°C



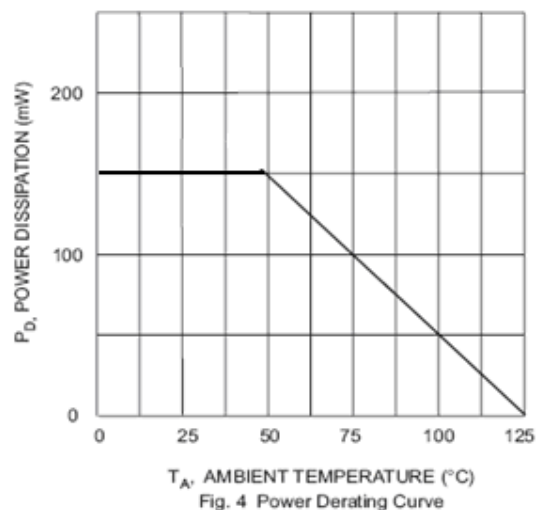
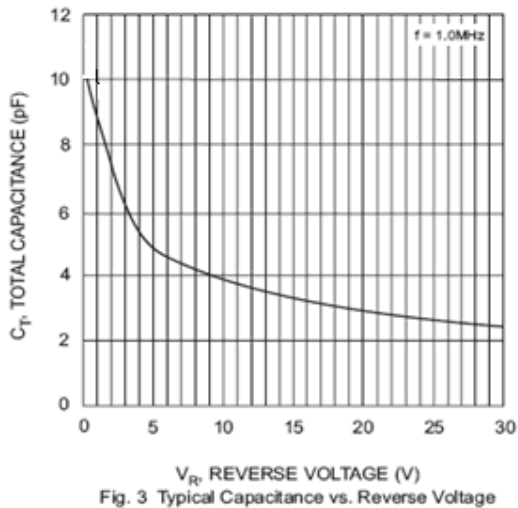
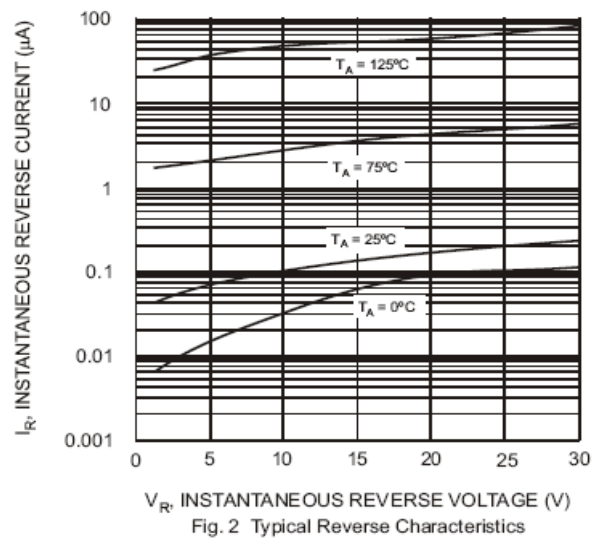
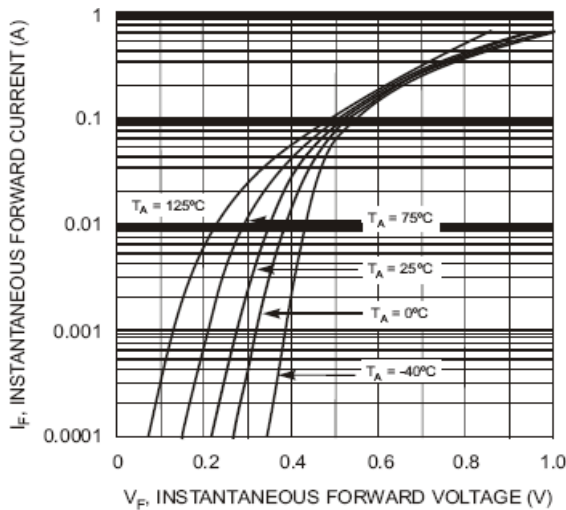
Surface Mount Schottky Barrier diode

**BAT54M/AM/CM/SM**

ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Reverse Breakdown Voltage	$V_{(BR)}$	30			V	$I_R=100\mu A$
Forward voltage	$V_{F1}$			0.24	V	$I_F=0.1mA$
				0.32	V	$I_F=1mA$
				0.40	V	$I_F=10mA$
				0.50	V	$I_F=30mA$
				1	V	$I_F=100mA$
Reverse current	$I_R$			2	$\mu A$	$V_R=25V$
Diode Capacitance	$C_D$			10	pF	$V_R=1V, f=1MHz$
Reverse Recovery Time	$t_{rr}$			5	ns	$I_F=I_R=10mA$ $I_{rr}=0.1I_R, R_L=100\Omega$

TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified



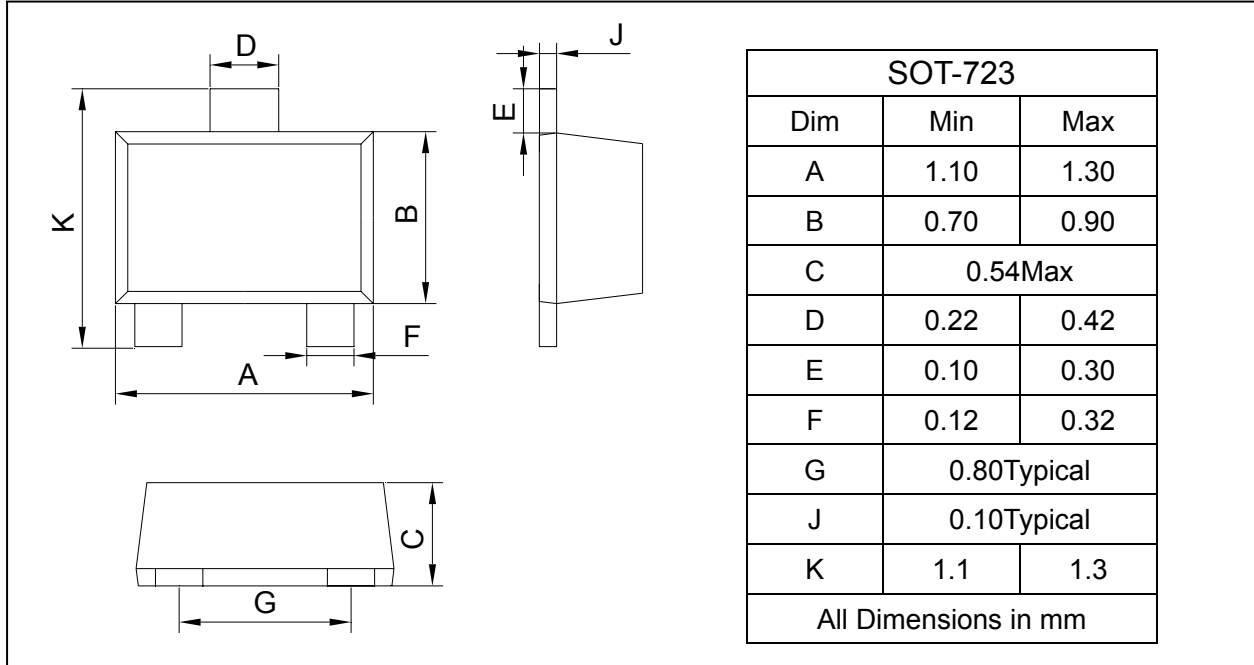
Surface Mount Schottky Barrier diode

**BAT54M/AM/CM/SM**

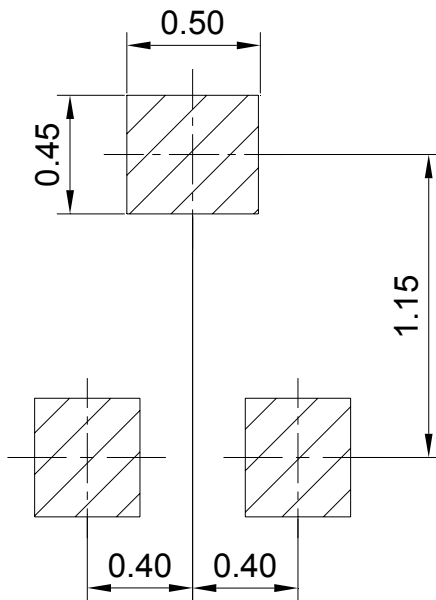
PACKAGE OUTLINE

Plastic surface mounted package

SOT-723



SOLDERING FOOTPRINT



PACKAGE INFORMATION

Device	Package	Shipping
BAT54M/AM/CM/SM	SOT-23	3000/Tape&Reel